

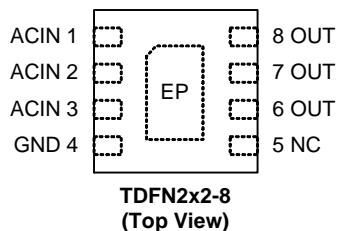
### Features

- **Input Over-Voltage Protection**
- **Over-Temperature Protection**
- **High Immunity of False Triggering**
- **High Accuracy Protection Thresholds**
- **Available in TDFN2x2-8 Package**
- **Lead Free and Green Devices Available (RoHS Compliant)**
- **Compliance to IEC61000-4-2 (Level 4)**  
 $\pm 8\text{kV}$  (Contact Discharge)  
 $\pm 15\text{kV}$  (Air Discharge)

### Applications

- **Smart Phones and PDAs**
- **Digital Still Cameras**
- **Portable Devices**

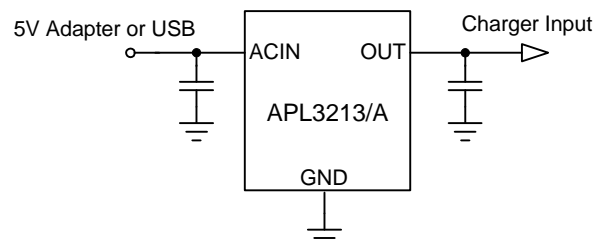
### Pin Configuration



### General Description

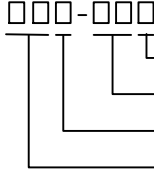
The APL3213/A provide Li+ charger protection against over-voltage. The IC is designed to monitor input voltage. When input voltage is over the threshold, the IC removes the power from the charging system by turning off an internal switch. The protection also have deglitch time against false triggering due to voltage spikes. The APL3213/A also provide Power-On-Reset (POR) function and over-temperature protection. The Power-On-Reset circuit monitors supply voltages to prevent wrong operations. The over-temperature protection limits the junction temperature below 140°C in case of short circuit or overload conditions.

### Simplified Application Circuit



ANPEC reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

## Ordering and Marking Information

|   |   |     |               |
|---|---|-----|---------------|
| APL3213/A    □□□-□□□<br> <ul style="list-style-type: none"> <li>— Assembly Material</li> <li>— Handling Code</li> <li>— Temperature Range</li> <li>— Package Code</li> </ul> | Package Code<br>QB : TDFN2x2-8<br>Operating Ambient Temperature Range<br>I : -40 to 85 °C<br>Handling Code<br>TR : Tape & Reel<br>Assembly Material<br>G : Halogen and Lead Free Device |     |               |
| APL3213 QB: <table border="1" style="display: inline-table; vertical-align: middle;"><tr><td style="text-align: center;">3213</td></tr><tr><td style="text-align: center;">● X</td></tr></table>  | 3213  | ● X | X - Date Code |
| 3213  |   |     |               |
| ● X   |   |     |               |
| APL3213A QB: <table border="1" style="display: inline-table; vertical-align: middle;"><tr><td style="text-align: center;">213A</td></tr><tr><td style="text-align: center;">● X</td></tr></table>   | 213A  | ● X | X - Date Code |
| 213A  |   |     |               |
| ● X   |   |     |               |

Note : ANPEC lead-free products contain molding compounds/die attach materials and 100% matte tin plate termination finish; which are fully compliant with RoHS. ANPEC lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J-STD-020D for MSL classification at lead-free peak reflow temperature. ANPEC defines “Green” to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

## Absolute Maximum Ratings (Note 1)

| Symbol     | Parameter                                      | Rating     | Unit |
|------------|--|------------|------|
| $V_{ACIN}$ | ACIN Input Voltage (ACIN pin to GND)           | -0.3 to 20 | V    |
| $V_{OUT}$  | OUT, Pin to GND Voltage                        | -0.3 to 7  | V    |
| $I_{OUT}$  | OUT Output Current                             | 2          | A    |
| $T_J$      | Maximum Junction Temperature                   | 150        | °C   |
| $T_{STG}$  | Storage Temperature Range                      | -65 to 150 | °C   |
| $T_{SDR}$  | Maximum Lead Soldering Temperature, 10 Seconds | 260        | °C   |

Note1: Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## Thermal Characteristics

| Symbol        | Parameter   | Typical Value | Unit |
|---------------|---|---------------|------|
| $\theta_{JA}$ | Junction to Ambient Thermal Resistance in Free Air <sup>(Note 2)</sup><br>TDFN2x2-8 | 75            | °C/W |

Note 2 :  $\theta_{JA}$  is measured with the component mounted on a high effective thermal conductivity test board in free air.

## Recommended Operating Conditions

| Symbol     | Parameter            | Range      | Unit        |   |
|------------|----------------------|------------|-------------|---|
| $V_{ACIN}$ | ACIN Input Voltage   | APL3213    | 4.5 to 5.5  | V |
|            |                      | APL3213A   | 4.5 to 5.25 | V |
| $I_{OUT}$  | OUT Output Current   | 0 to 1.5   | A           |   |
| $T_J$      | Junction Temperature | -40 to 125 | °C          |   |
| $T_A$      | Ambient Temperature  | -40 to 85  | °C          |   |

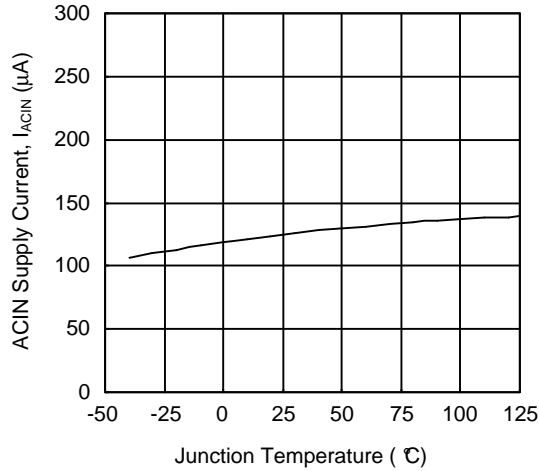
## Electrical Characteristics

Refer to the typical application circuit. These specifications apply over  $V_{ACIN}=5V$ ,  $T_A=-40\sim85^{\circ}C$ , unless otherwise specified. Typical values are at  $T_A=25^{\circ}C$ .

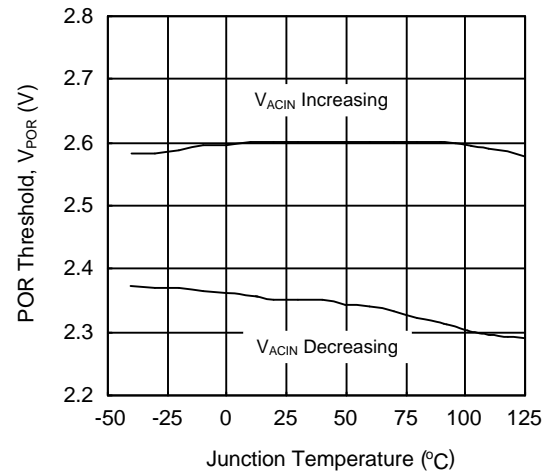
| Symbol  | Parameter                     | Test Conditions                       | APL3213/A                             |       |      | Unit        |   |
|---|-------------------------------|---------------------------------------|---------------------------------------|-------|------|-------------|---|
|   |                               |                                       | Min.                                  | Typ.  | Max. |             |   |
| <b>POWER-ON-RESET (POR) AND SUPPLY CURRENT</b>            |                               |                                       |                                       |       |      |             |   |
| $V_{POR}$   | ACIN POR Threshold            | $V_{ACIN}$ rising                     | 2.4                                   | -     | 2.8  | V           |   |
|   | ACIN POR Hysteresis           |                                       | -                                     | 250   | -    | mV          |   |
| $I_{CC}$  | ACIN Supply Current           |                                       | -                                     | 125   | 300  | $\mu A$     |   |
| $T_{B(ACIN)}$   | Input Power-On Blanking Time  | $V_{ACIN}$ rising to $V_{OUT}$ rising | -                                     | 8     | -    | ms          |   |
| <b>INTERNAL POWER SWITCH AND OUT DISCHARGE RESISTANCE</b> |                               |                                       |                                       |       |      |             |   |
|   | Power Switch On Resistance    | $I_{OUT} = 0.6A$                      | -                                     | 130   | -    | $m\Omega$   |   |
|   | OUT Discharge Resistance      | $V_{OUT} = 3V$                        | -                                     | 500   | -    | $\Omega$    |   |
| <b>INPUT OVER-VOLTAGE PROTECTION (OVP)</b>                |                               |                                       |                                       |       |      |             |   |
| $V_{OVP}$   | Input OVP Threshold           | $V_{ACIN}$ rising                     | APL3213                               | 5.70  | 5.85 | 6.00        | V |
|   |                               |                                       | APL3213A, $T_A=25^{\circ}C$           | 5.285 | 5.33 | 5.38        | V |
|   |                               |                                       | APL3213A,<br>$T_A=-20\sim60^{\circ}C$ | 5.28  | 5.33 | 5.4         | V |
|   | Input OVP Recovery Hysteresis |                                       | 150                                   | 250   | 350  | mV          |   |
|   | Input OVP Propagation Delay   |                                       | -                                     | 1     | -    | $\mu s$     |   |
| $T_{ON(OVP)}$   | Input OVP Recovery Time       |                                       | -                                     | 8     | -    | ms          |   |
| <b>OVER-TEMPERATURE PROTECTION (OTP)</b>                  |                               |                                       |                                       |       |      |             |   |
| $T_{OTP}$   | Over-Temperature Threshold    |                                       | -                                     | 140   | -    | $^{\circ}C$ |   |
|   | Over-Temperature Hysteresis   |                                       | -                                     | 20    | -    | $^{\circ}C$ |   |

## Typical Operating Characteristics

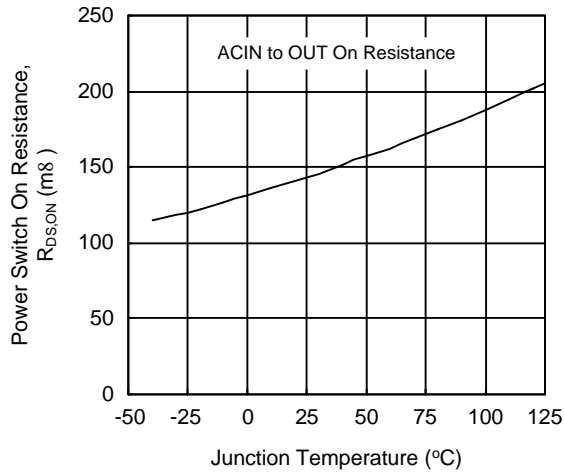
**ACIN Supply Current vs. Junction Temperature**



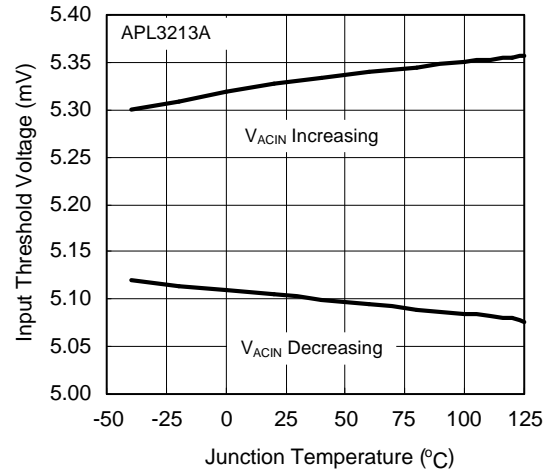
**POR Threshold vs. Junction Temperature**



**Power Switch On Resistance vs. Junction Temperature**



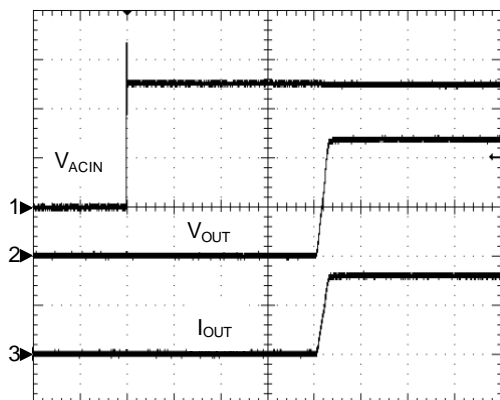
**Input OVP Threshold vs. Junction Temperature**



## Operating Waveforms

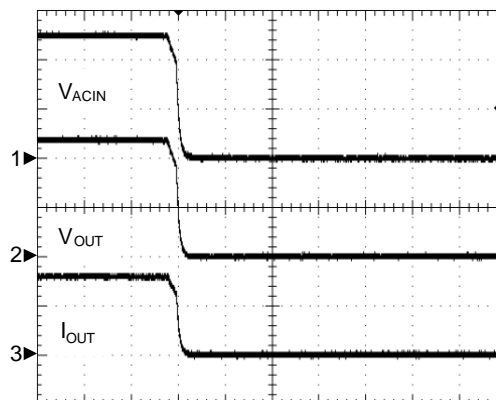
Refer to the typical application circuit. The test condition is  $V_{ACIN} = 5V$ ,  $C_{ACIN} = 1\mu F$ ,  $C_{OUT} = 1\mu F$ ,  $T_A = 25^\circ C$  unless otherwise specified.

Normal Power On



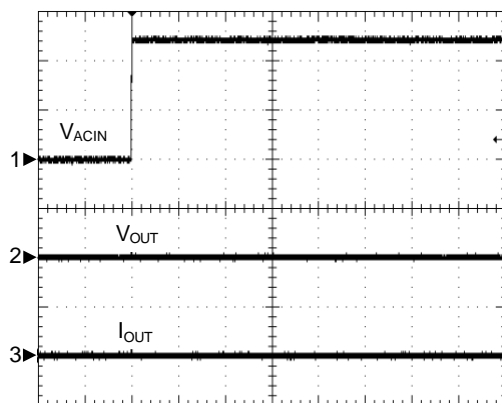
$R_{OUT} = 3\Omega$   
 CH1:  $V_{ACIN}$ , 2V/Div, DC  
 CH2:  $V_{OUT}$ , 2V/Div, DC  
 CH3:  $I_{OUT}$ , 1A/Div, DC  
 TIME: 2ms/Div

Normal Power Off



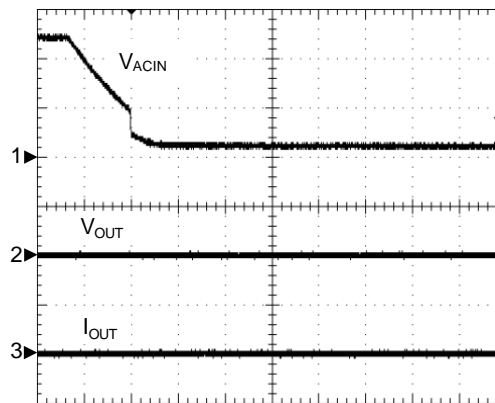
$R_{OUT} = 3\Omega$   
 CH1:  $V_{ACIN}$ , 2V/Div, DC  
 CH2:  $V_{OUT}$ , 2V/Div, DC  
 CH3:  $I_{OUT}$ , 1A/Div, DC  
 TIME: 100 $\mu$ s/Div

OVP at Power On



$V_{ACIN} = 0$  to 12V  
 CH1:  $V_{ACIN}$ , 5V/Div, DC  
 CH2:  $V_{OUT}$ , 2V/Div, DC  
 CH3:  $I_{OUT}$ , 1A/Div, DC  
 TIME: 2ms/Div

OVP at Power Off

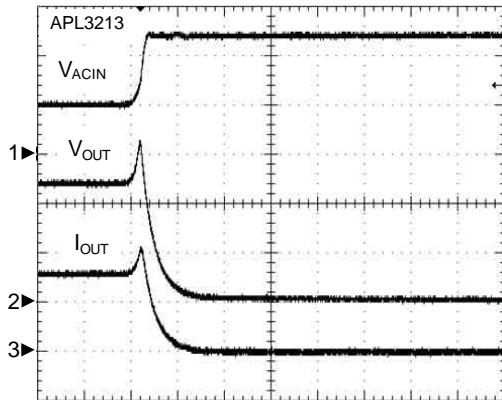


$V_{ACIN} = 12$  to 0V  
 CH1:  $V_{DD}$ , 5V/Div, DC  
 CH2:  $V_{OUT}$ , 2V/Div, DC  
 CH3:  $I_{OUT}$ , 1A/Div, DC  
 TIME: 40ms/Div

## Operating Waveforms

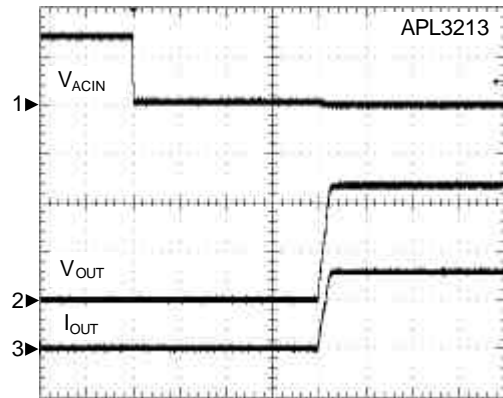
Refer to the typical application circuit. The test condition is  $V_{ACIN} = 5V$ ,  $C_{ACIN} = 1\mu F$ ,  $C_{OUT} = 1\mu F$ ,  $T_A = 25^\circ C$  unless otherwise specified.

### Input Over-Voltage Protection



$V_{ACIN} = 5 \text{ to } 12V$ ,  $R_{OUT} = 3\Omega$   
 CH1:  $V_{ACIN}$ , 5V/Div, DC  
 CH2:  $V_{CHIN}$ , 2V/Div, DC  
 CH3:  $I_{OUT}$ , 1A/Div, DC  
 TIME: 10 $\mu$ s/Div

### Recovery from Input OVP

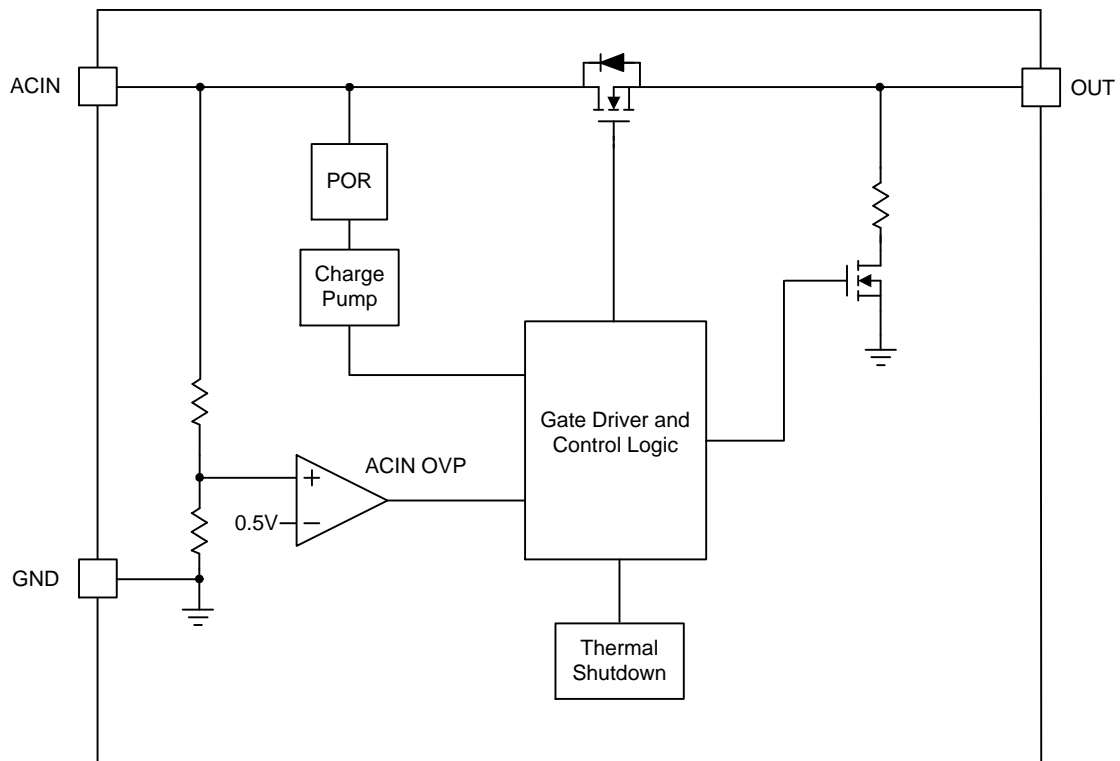


$V_{ACIN} = 12 \text{ to } 5V$ ,  $R_{OUT} = 3\Omega$   
 CH1:  $V_{ACIN}$ , 5V/Div, DC  
 CH2:  $V_{CHIN}$ , 2V/Div, DC  
 CH3:  $I_{OUT}$ , 1A/Div, DC  
 TIME: 2ms/Div

### Pin Description

| PIN     |      | FUNCTION  |
|---------|------|---|
| NO.     | NAME |   |
| 1, 2, 3 | ACIN | Power Supply Input.   |
| 4       | GND  | Ground.   |
| 5       | NC   | No Connection.  |
| 6, 7, 8 | OUT  | Output Voltage Pin. The output voltage follows the input voltage when no fault is detected. |
| -       | EP   | Exposed Thermal Pad. Must be electrically connected to the GND pin.                         |

### Block Diagram



## Typical Application Circuit

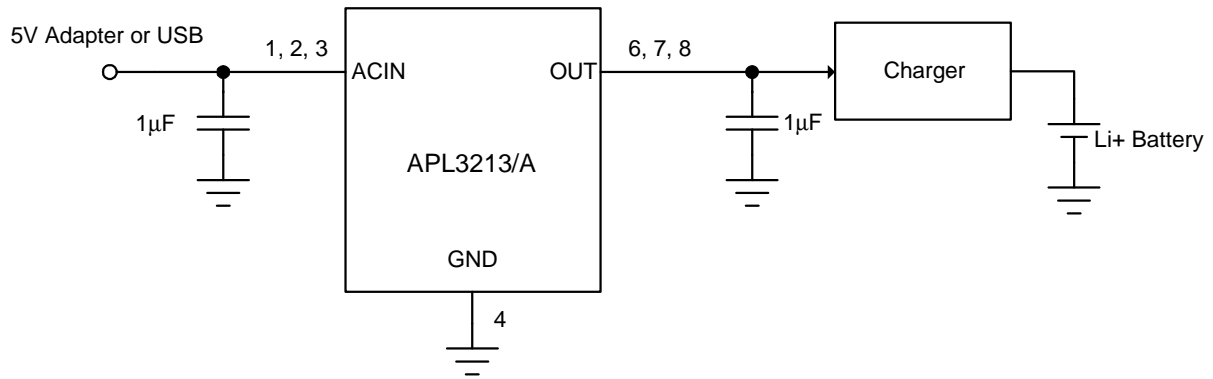


Figure 1. The Typical Protection Circuit for Charger Systems.



## Function Description

### Power-Up

The APL3213/A have a built-in power-on-reset circuit to keep the output shutting off until internal circuitry is operating properly. The POR circuit has hysteresis and a deglitch feature so that it will typically ignore undershoot transients on the input. When input voltage exceeds the POR threshold and after 8ms blanking time, the output voltage starts a soft-start to reduce the inrush current.

### Input Over-Voltage Protection (OVP)

The input voltage is monitored by the internal OVP circuit. When the input voltage rises above the input OVP threshold, the internal FET will be turned off within 1 $\mu$ s to protect connected system on OUT pin. When the input voltage returns below the input OVP threshold minus the hysteresis, the FET is turned on again after 8ms recovery time. The input OVP circuit has a 200mV hysteresis and a recovery time of  $T_{ON(OVP)}$  to provide noise immunity against transient conditions.

### Over-Temperature Protection

When the junction temperature exceeds 140°C, the internal thermal sense circuit turns off the power FET and allows the device to cool down. When the device's junction temperature cools by 20°C, the internal thermal sense circuit will enable the device, resulting in a pulsed output during continuous thermal protection. Thermal protection is designed to protect the IC in the event of over-temperature conditions. For normal operation, the junction temperature cannot exceed  $T_J=+125^\circ\text{C}$ .

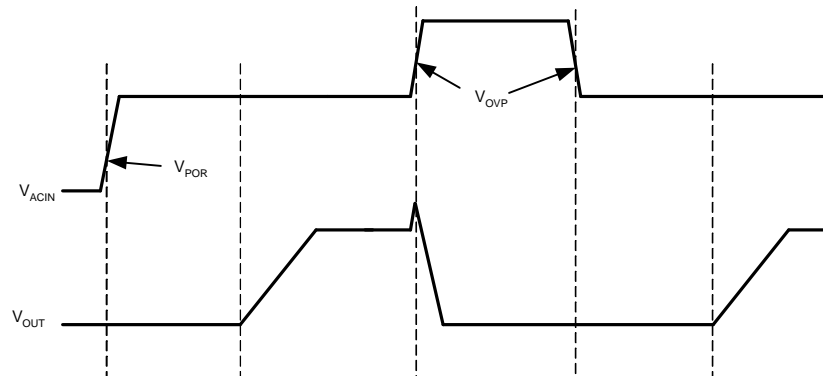


Figure 2. OVP Timing Chart

## Application Information

### Capacitor Selection

The input capacitor is for decoupling and prevents the input voltage from overshooting to dangerous levels. In the AC adapter hot plug-in applications or load current step-down transient, the input voltage has a transient spike due to the parasitic inductance of the input cable. A 25V, X5R, dielectric ceramic capacitor with a value between 1 $\mu$ F and 4.7 $\mu$ F placed close to the ACIN pin is recommended.

The output capacitor is for output voltage decoupling, and also the input capacitor of the charging circuit.

At least, a 1 $\mu$ F, 10V, X5R capacitor is recommended.

### Layout Consideration

In some failure modes, a high voltage may be applied to the device. Make sure the clearance constraint of the PCB layout must satisfy the design rule for high voltage.

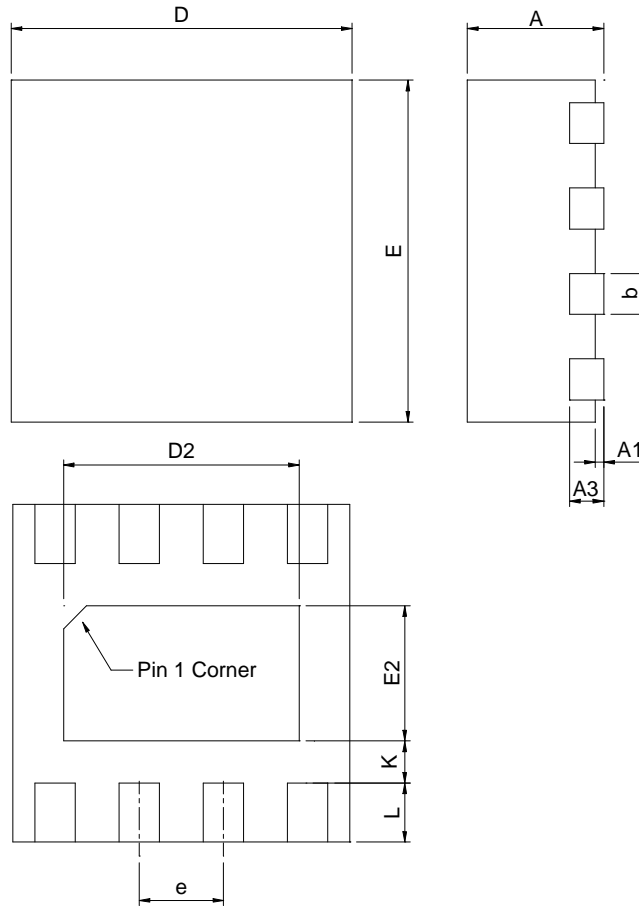
The exposed pad of the TDFN2x2-8 performs the function of channeling heat away. It is recommended that connect the exposed pad to a large copper ground plane on the backside of the circuit board through several thermal vias to improve heat dissipation.

The input and output capacitors should be placed close to the IC.

The high current traces like input trace and output trace must be wide and short.

Package Information

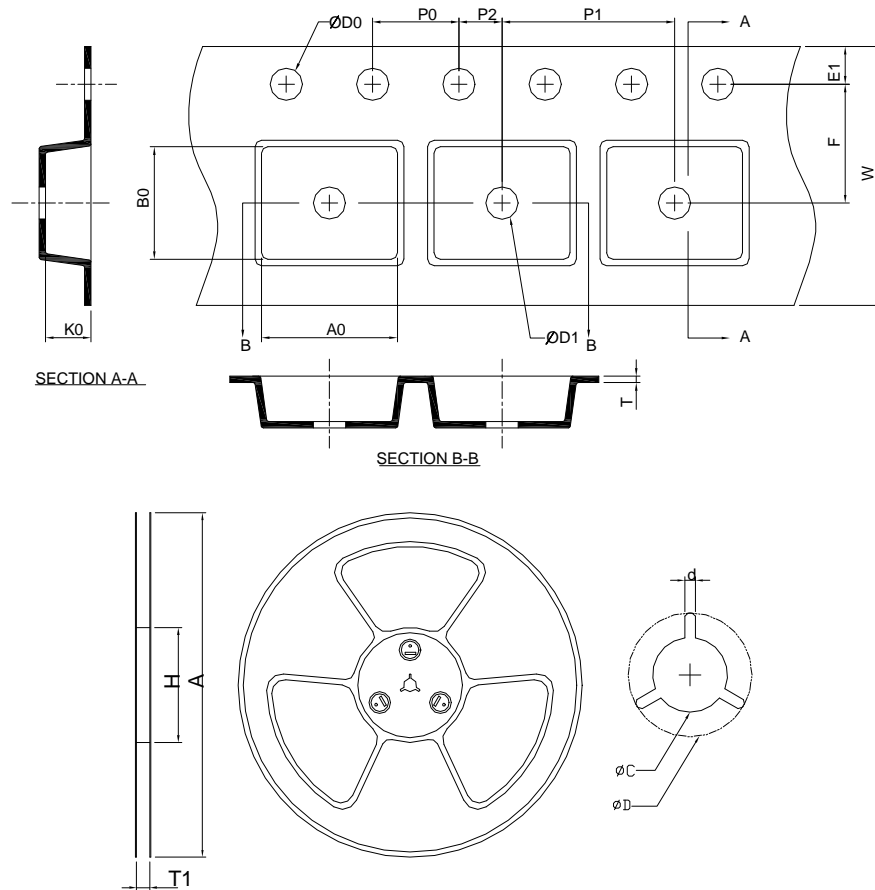
TDFN2x2-8



| SYMBOL | TDFN2x2-8   |      |           |       |
|--------|-------------|------|-----------|-------|
|        | MILLIMETERS |      | INCHES    |       |
|        | MIN.        | MAX. | MIN.      | MAX.  |
| A      | 0.70        | 0.80 | 0.028     | 0.031 |
| A1     | 0.00        | 0.05 | 0.000     | 0.002 |
| A3     | 0.20 REF    |      | 0.008 REF |       |
| b      | 0.18        | 0.30 | 0.007     | 0.012 |
| D      | 1.90        | 2.10 | 0.075     | 0.083 |
| D2     | 1.00        | 1.60 | 0.039     | 0.063 |
| E      | 1.90        | 2.10 | 0.075     | 0.083 |
| E2     | 0.60        | 1.00 | 0.024     | 0.039 |
| e      | 0.50 BSC    |      | 0.020 BSC |       |
| L      | 0.30        | 0.45 | 0.012     | 0.018 |
| K      | 0.20        |      | 0.008     |       |

Note : 1. Followed from JEDEC MO-229 WCCD-3.

### Carrier Tape & Reel Dimensions



| Application | A           | H         | T1                | C                  | d         | D                | W         | E1         | F          |
|-------------|-------------|-----------|-------------------|--------------------|-----------|------------------|-----------|------------|------------|
| TDFN2x2-8   | 178.0 ±2.00 | 50 MIN.   | 8.4+2.00<br>-0.00 | 13.0+0.50<br>-0.20 | 1.5 MIN.  | 20.2 MIN.        | 8.0 ±0.20 | 1.75 ±0.10 | 3.50 ±0.05 |
|             | <b>P0</b>   | <b>P1</b> | <b>P2</b>         | <b>D0</b>          | <b>D1</b> | <b>T</b>         | <b>A0</b> | <b>B0</b>  | <b>K0</b>  |
|             | 4.0 ±0.10   | 4.0 ±0.10 | 2.0 ±0.05         | 1.5+0.10<br>-0.00  | 1.5 MIN.  | 0.6+0.00<br>-0.4 | 3.35 MIN  | 3.35 MIN   | 1.30 ±0.20 |

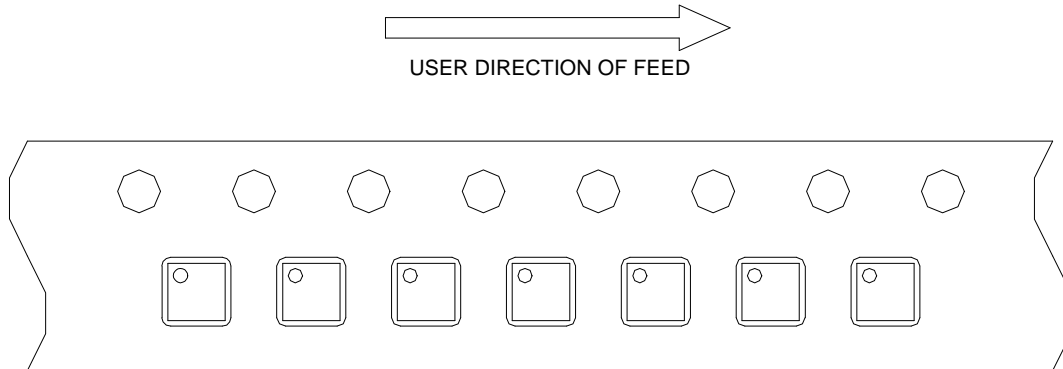
(mm)

### Devices Per Unit

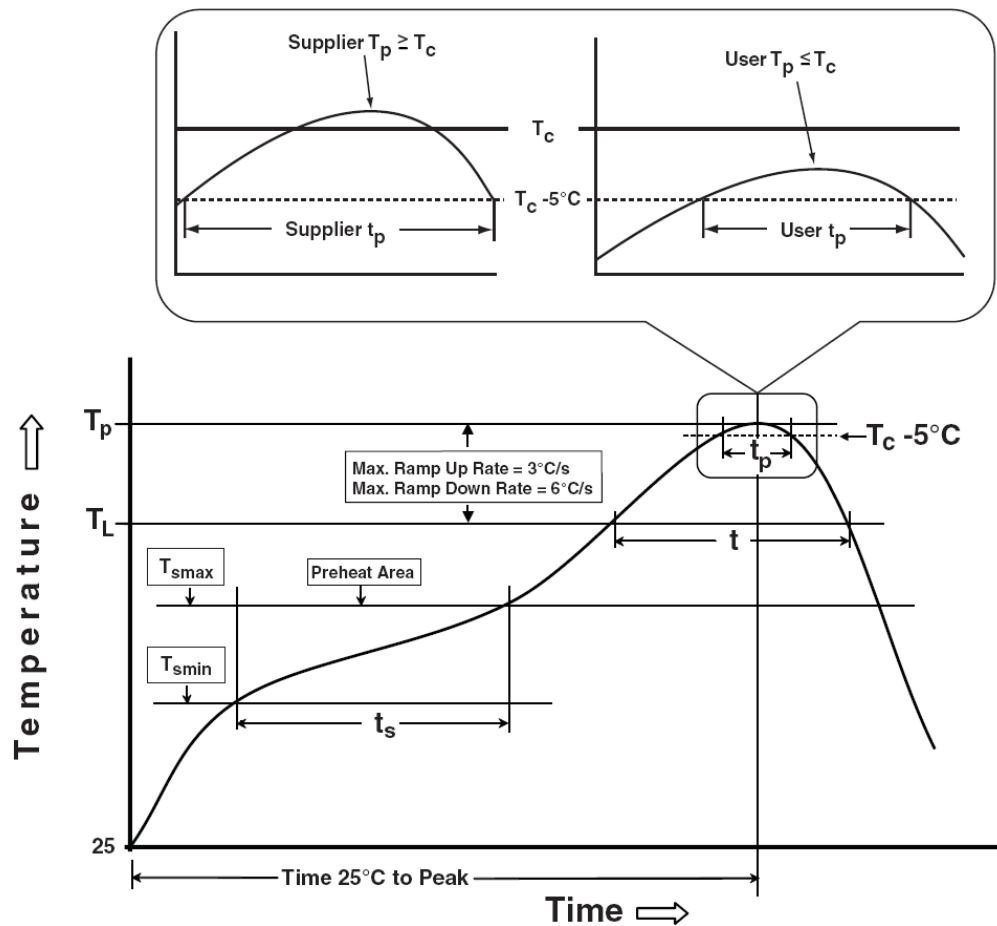
| Package Type | Unit        | Quantity |
|--------------|-------------|----------|
| TDFN2x2-8    | Tape & Reel | 3000     |

## Taping Direction Information

TDFN2x2-8



## Classification Profile



## Classification Reflow Profiles

| Profile Feature  | Sn-Pb Eutectic Assembly            | Pb-Free Assembly                   |
|--|------------------------------------|------------------------------------|
| <b>Preheat &amp; Soak</b>  |                                    |                                    |
| Temperature min ( $T_{smin}$ )   | 100 °C                             | 150 °C                             |
| Temperature max ( $T_{smax}$ )   | 150 °C                             | 200 °C                             |
| Time ( $T_{smin}$ to $T_{smax}$ ) ( $t_s$ )  | 60-120 seconds                     | 60-120 seconds                     |
| Average ramp-up rate ( $T_{smax}$ to $T_p$ )   | 3 °C/second max.                   | 3 °C/second max.                   |
| Liquidous temperature ( $T_L$ )  | 183 °C                             | 217 °C                             |
| Time at liquidous ( $t_L$ )  | 60-150 seconds                     | 60-150 seconds                     |
| Peak package body Temperature ( $T_p$ )*   | See Classification Temp in table 1 | See Classification Temp in table 2 |
| Time ( $t_p$ )** within 5°C of the specified classification temperature ( $T_c$ )                                | 20** seconds                       | 30** seconds                       |
| Average ramp-down rate ( $T_p$ to $T_{smax}$ )   | 6 °C/second max.                   | 6 °C/second max.                   |
| Time 25°C to peak temperature  | 6 minutes max.                     | 8 minutes max.                     |
| * Tolerance for peak profile Temperature ( $T_p$ ) is defined as a supplier minimum and a user maximum.          |                                    |                                    |
| ** Tolerance for time at peak profile temperature ( $t_p$ ) is defined as a supplier minimum and a user maximum. |                                    |                                    |

Table 1. SnPb Eutectic Process – Classification Temperatures ( $T_c$ )

| Package Thickness | Volume mm <sup>3</sup><br><350 | Volume mm <sup>3</sup><br>≥350 |
|-------------------|--------------------------------|--------------------------------|
| <2.5 mm           | 235 °C                         | 220 °C                         |
| ≥2.5 mm           | 220 °C                         | 220 °C                         |

Table 2. Pb-free Process – Classification Temperatures ( $T_c$ )

| Package Thickness | Volume mm <sup>3</sup><br><350 | Volume mm <sup>3</sup><br>350-2000 | Volume mm <sup>3</sup><br>>2000 |
|-------------------|--------------------------------|------------------------------------|---------------------------------|
| <1.6 mm           | 260 °C                         | 260 °C                             | 260 °C                          |
| 1.6 mm – 2.5 mm   | 260 °C                         | 250 °C                             | 245 °C                          |
| ≥2.5 mm           | 250 °C                         | 245 °C                             | 245 °C                          |

## Reliability Test Program

| Test item     | Method             | Description                              |
|---------------|--------------------|--|
| SOLDERABILITY | JESD-22, B102      | 5 Sec, 245°C                             |
| HOLT          | JESD-22, A108      | 1000 Hrs, Bias @ $T_j=125^\circ\text{C}$ |
| PCT           | JESD-22, A102      | 168 Hrs, 100%RH, 2atm, 121°C             |
| TCT           | JESD-22, A104      | 500 Cycles, -65°C~150°C                  |
| HBM           | MIL-STD-883-3015.7 | VHBM 2KV                                 |
| MM            | JESD-22, A115      | VMM 200V                                 |
| Latch-Up      | JESD 78            | 10ms, 1 <sub>tr</sub> 100mA              |

## **Customer Service**

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